

The Interactions of Ferroelectric Domain Walls and Crystallographic Defects in the PbTiO₃ Films

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Both domain walls and lattice defects are known to have great influences on the properties of a ferroelectric, the detailed interactions between them and the resultant novel phenomena are still less known. In the tetragonal ferroelectrics, previous experimental investigations indicate that misfit dislocations form at film deposition temperature when PbTiO₃(PTO) is cubic with a relatively larger lattice constant compared to SrTiO₃(STO), while these dislocations may further promote the nucleation of α -domain [1,2]. However, these studies were mainly concentrated on the interactions between 90° domain walls and dislocations near the hetero-interface, indicating that a systematic observation on the interactions between dislocations and 90° domain walls is required.

In addition, the effects of 180° and charged domain walls which exhibit little strain were less studied previously due to the lack of instrumental resolution. Although some theoretical calculations about the interaction between dislocations and 90°/180° domain walls have been conducted [3], they are not revealed so far in experiments. Particularly, the atomic details and the local strain interactions were unattainable in these methods.

With the recent development of aberration-corrected (scanning) transmission electron microscope (Cs-(S)TEM), direct mapping of domain walls at the atomic scale becomes possible [4-7]. For instance, systematic investigations on 180° domain wall and 90° charged domain wall in tetragonal ferroelectrics reveal the different width and polarization characteristics at these domain walls compared to the uncharged one. Nevertheless, spatial coupling between defects and domain wall in PTO film are still not well understood.

The PTO films with the thickness of 40nm and 80nm, respectively, were deposited on STO (001) substrate by pulsed laser deposition technique. The KrF ($\lambda = 248$ nm) excimer with a laser energy density of 2 Jcm⁻² was used. Prior to deposition, the substrate was heated to 750°C and maintained for 5 min to clean the substrate surface and the target was pre-sputtered for 30 min to make sure their surfaces clean. When depositing PTO films, the substrate temperature was maintained at 650°C. An oxygen pressure of 20 Pa and a laser repetition rate of 5 Hz were used. After deposition, the film was annealed in an oxygen pressure of 5×10⁴ Pa at 650°C for 10 min, and then cooled down to room temperature with a cooling rate of about 5°C/min.

Basis on Cs-(S)TEM imaging, we extensively analyze domain patterns and unusual strain state caused by the complex interactions between lattice defects and ferroelectric domains in PTO films [8]. We find that: (1) a specific defect-domain wall interaction may give rise to a metastable domain configuration, such as unstable α - and c -domain, charged 90° domain walls as well as super-domain patterns. The relaxation of such metastable domain configurations is observed which may induce retention failure; (2)

90° domain walls are usually accompanied with specific dislocations along the 90° domain walls. In addition, unusual dislocation strain field which is along 90° domain wall is revealed. Such a strain field deviates 45° from that of the typical dislocation with an $a[0\bar{1}0]$ vector [9].

References:

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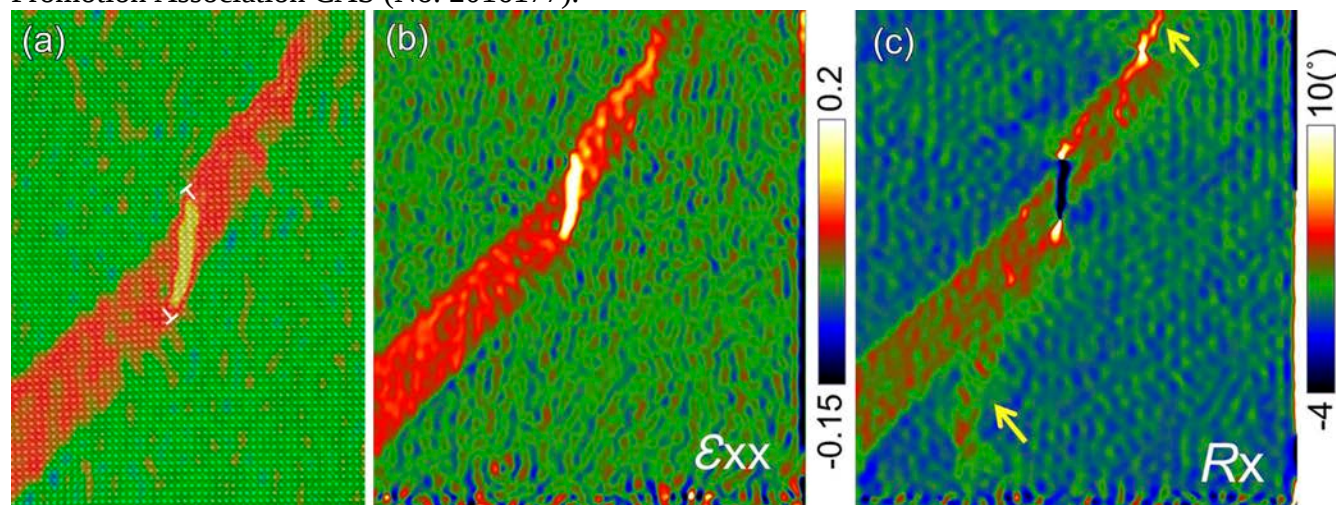


Figure 1. (a) A superimposition of HAADF-STEM images of PbTiO₃ and corresponding in-plane lattice strain map, where a -domain is in red and c -domain is in green. The notation of “T” denotes dislocations. This image implies that a -domain changes its extending direction when it comes across dislocations. (b) In-plane strain (ϵ_{xx}) and (c) lattice rotation (R_x) maps of (a) [8].